

CRYSTALLIZATION KINETICS FOR THE SYSTEM CuSO₄-ZnSO₄-H₂O FORMING SOLID SOLUTIONS

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The three-component system CuSO₄-ZnSO₄-H₂O forms three types of solid solution. Metastable zone widths measured for selected solution compositions at two cooling rates were used to calculate the kinetic parameters of nucleation. The rate of crystal growth was measured by the fluidized bed method. The results show that the addition of Zn²⁺ to a solution of CuSO₄ increases both the nucleation and crystal growth rates, whereas Cu²⁺ added to a solution of ZnSO₄ retards the nucleation rate and slightly increases the rate of crystal growth. The nucleation rate (the metastable zone width) is substantially more sensitive to the addition of a second component than is the rate of crystal growth. The crystal growth rate is controlled by a diffusion mechanism.

As shown by an analysis of data on phase equilibria in the system CuSO₄-ZnSO₄-H₂O, this system forms three types of solid solution¹: triclinic CuSO₄.5 H₂O with an isomorphous admixture of ZnSO₄ (further designated as Cu/Zn) which crystallizes from solutions rich in CuSO₄; rhombic ZnSO₄ isomorphously contaminated by CuSO₄ (Zn/Cu system) which crystallizes in the region of high ZnSO₄ concentrations; and zinc sulphate ZnSO₄.7 H₂O with a substantial admixture of CuSO₄ causing a change to the monoclinic type of lattice (ZnCu/Cu system), this solid solution being the equilibrium solid phase in the intermediate concentration range.

The aim of the present work was to investigate the effect of the formation of solid solutions on the nucleation and crystal growth kinetics.

In describing the nucleation kinetics, we use the conventional power law

$$\dot{N}_N = k_N \Delta w^n. \quad (1)$$

The kinetic measurements consist of measuring the metastable zone width as a function of the cooling rate². The calculation is made using the equations

$$\log \Delta T_{\max} = A + \frac{1}{n} \log(-\dot{T}) \quad (2)$$

and

$$\log k_N = (1 - n) \log(dw_{\text{eq}}/dT) - An. \quad (3)$$

The measurement of the crystal growth rate,

$$\dot{m}_G = k_G A_c \Delta w^g, \quad (4)$$

by the fluidized bed method is based on following the mass gain of crystals^{3,4} fluidized by an upward stream of solution having a known supersaturation,

$$\dot{L} = (m_f^{1/3} - m_0^{1/3}) / t (\alpha \rho_c N_c)^{1/3}. \quad (5)$$

The order of the crystal growth rate, g , is obtained from the linear equation

$$\log \dot{L} = \log \dot{L}_0 + g \log \Delta w, \quad (6)$$

and the rate constant can be calculated as

$$k_G = 3\alpha \rho_c \dot{L} / \beta \Delta w^g. \quad (7)$$

EXPERIMENTAL

Solutions of $\text{CuSO}_4 \cdot 5 \text{H}_2\text{O}$ (analytical grade; Lachema) and $\text{ZnSO}_4 \cdot 7 \text{H}_2\text{O}$ (analytical grade; Lachema) were made up in distilled water. The solution compositions were checked analytically (by complexometric titration for Zn and iodometric titration for Cu). The equilibrium saturation temperatures were determined by the last-crystal-dissolving method⁵. The solutions prepared are indicated on the phase diagram in Fig. 1, and their compositions are given in Table I.

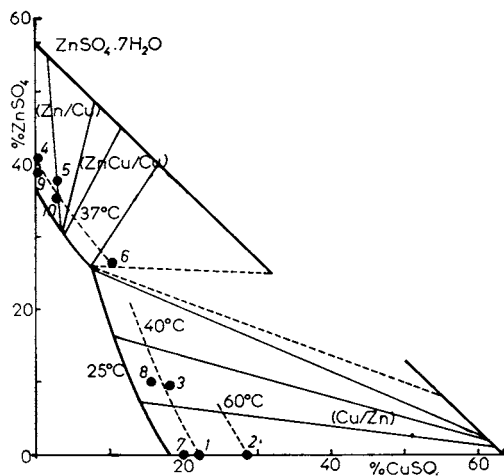


FIG. 1
Phase diagram of the system CuSO_4 -
 ZnSO_4 - H_2O with indication of solution
compositions used for measurements

The metastable zone width was measured by a method described in the literature^{2,6}: a solution saturated at temperature T_{eq} was placed in a magnetically stirred Erlenmeyer flask together with one or two large crystals of pure $\text{CuSO}_4 \cdot 5 \text{H}_2\text{O}$ or $\text{ZnSO}_4 \cdot 7 \text{H}_2\text{O}$ and cooled at a constant rate ($-\dot{T}$) until the first crystals of the newly precipitated phase appeared. The solution was subsequently heated slowly until the crystals dissolved. The difference between the two temperatures gives the maximum undercooling ΔT_{max} . The temperature was measured with a Pt resistance

TABLE I
Solution compositions

Solution No	mass % CuSO_4	mass % ZnSO_4	Solution No	mass % CuSO_4	mass % ZnSO_4
1	22.2	0	6	9.8	25.7
2	28.8	0	7	20.0	0
3	18.3	9.9	8	15.5	10.0
4	0	40.5	9	0	39.0
5	3.0	38.0	10	3.0	35.5

TABLE II
Metastable zone widths for the system $\text{CuSO}_4\text{-ZnSO}_4\text{-H}_2\text{O}$

System No	T_{eq} °C	$-\dot{T}$ K h^{-1}	Number of runs	ΔT_{max} exper. ^a	n^a	A	ΔT_{max} calc.
1	40	2	15	4.3 ± 0.4	3.29 ± 0.7	1.619	4.26
		20	20	8.6 ± 0.6			8.58
2	60	2	6	1.9 ± 0.1	2.84 ± 0.4	1.429	1.92
		20	6	4.3 ± 0.3			4.31
3	40	2	12	2.9 ± 0.2	2.51 ± 0.3	1.755	2.87
		20	13	7.2 ± 0.4			7.19
4	37	2	34	1.1 ± 0.1	2.97 ± 0.6	1.139	1.10
		20	20	2.4 ± 0.2			2.40
5	37	2	6	1.4 ± 0.04	2.19 ± 0.2	1.624	1.37
		6	2	2.25 ± 0.07			
		20	28	4.0 ± 0.04			3.93
6	37	2	14	1.9 ± 0.1	2.43 ± 0.25	1.628	1.94
		20	18	5.0 ± 0.2			5.01

^a Supplemented with the standard deviation.

thermometer which simultaneously controlled a thermoregulator with digital adjustment of the cooling rate. Results of the measurements are summarized in Table II.

The crystal growth kinetics were measured using an apparatus shown in Fig. 2. A slightly undersaturated solution was pumped through a cooler 4, where the required supersaturation was produced, into a measuring tube 6 with a fluidized layer of growing crystals. On passing through the layer, it returned via a flowmeter 11 back to the storage reservoir 1. A known number of crystals, N_c , of known initial mass, m_0 , was allowed to grow for a time period, t , in a solution of known supersaturation

$$\Delta w = (T_{eq} - T) (dw_{eq}/dT). \quad (8)$$

As the saturation temperature, T_{eq} , was difficult to determine rapidly and with sufficient accuracy, it was obtained by extrapolation of data for the crystal growth rate, \dot{L} , as a function of temperature, T , to zero \dot{L} . The accuracy of the linear extrapolation was verified in one case by an experiment in which the crystals were dissolved in an undersaturated solution. The saturation temperatures ranged between 27 and 33°C. The crystal shape factors⁷ were as follows: $\text{CuSO}_4 \cdot 5 \text{H}_2\text{O} - \alpha = 0.288, \beta = 3.01$; $\text{ZnSO}_4 \cdot 7 \text{H}_2\text{O} - \alpha = 2.714, \beta = 12.86$. The measurements were always performed at a minimum of two flow rates of solution, v . A survey of the measurements is given in Table III and in Figs 3–6.

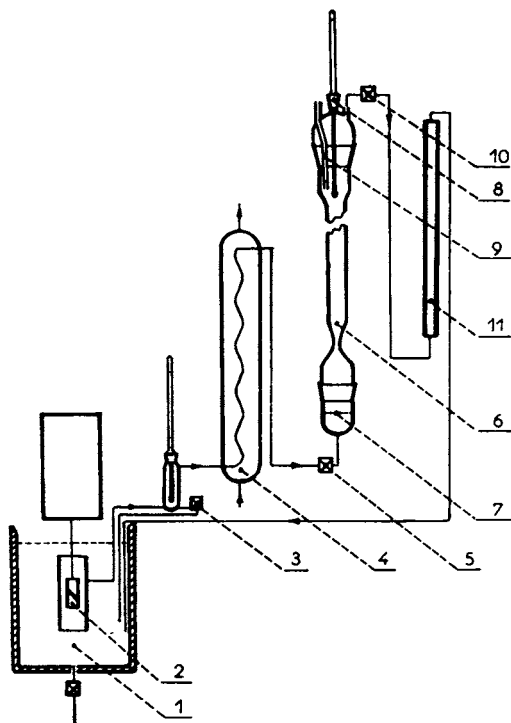


FIG. 2

Apparatus for fluidized-bed measurement of crystal growth rate. 1 stock solution; 2 pump; 3, 5, 10 valves; 4 cooler; 6 measuring tube; 7 fritted glass; 8 thermometer; 9 crystal input tube; 11 flowmeter

DISCUSSION AND CONCLUSIONS

The solution compositions indicated in Fig. 1 were chosen so as to make it possible to assess to what extent and in what sense the addition of a second component

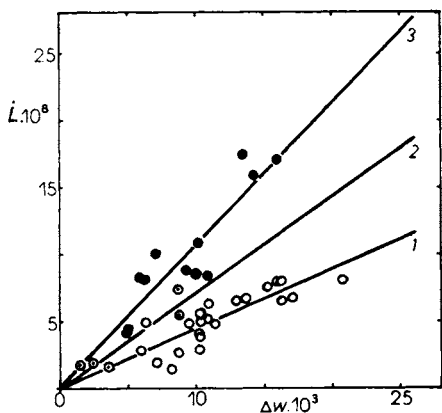


FIG. 3

Linear crystallization rate for CuSO_4 (System No 7). 1 $v = 2.6 \text{ cm s}^{-1}$; 2 $v = 4 \text{ cm s}^{-1}$; 3 $v = 5 \text{ cm s}^{-1}$

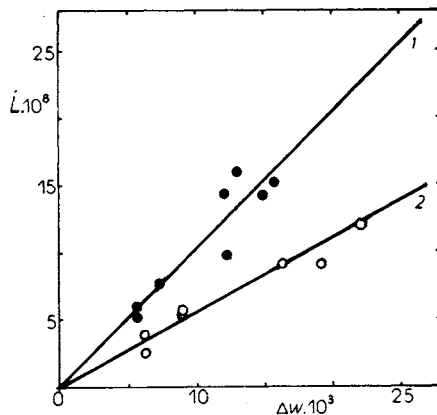


FIG. 4

Linear crystallization rate for CuSO_4 with an admixture of ZnSO_4 (System No 8). 1 $v = 5 \text{ cm s}^{-1}$; 2 $v = 2.6 \text{ cm s}^{-1}$

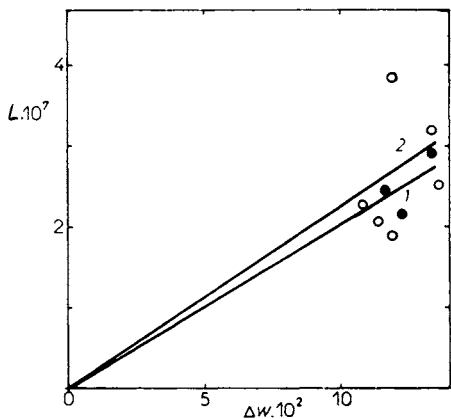


FIG. 5

Linear crystallization rate for ZnSO_4 (System No 9). 1 $v = 1.8 \text{ cm s}^{-1}$; 2 $v = 2.8 \text{ cm s}^{-1}$

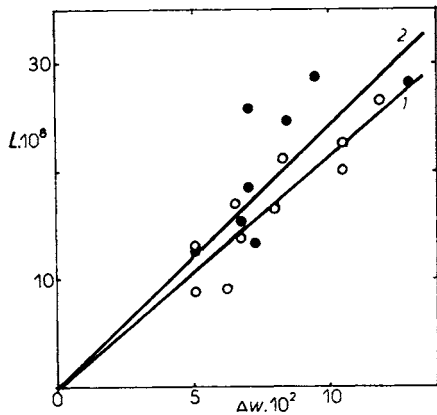


FIG. 6

Linear crystallization rate for ZnSO_4 with an admixture of CuSO_4 (System No 10). 1 $v = 1.8 \text{ cm s}^{-1}$; 2 $v = 2.8 \text{ cm s}^{-1}$

affects the crystallization behaviour of the main component. As indicated by the data listed in Table II, the addition of ZnSO_4 to CuSO_4 as the major component decreases the metastable zone width whereas the addition of CuSO_4 to ZnSO_4 has the opposite effect. A quantitative comparison of the data is however difficult to make because the nucleation exponents, n , for the systems somewhat differ. On closer examination, however, it turns out that the nucleation exponents for systems 1 to 3, and similarly for systems 4 to 6, may be regarded as identical within the scatter considered, and hence the data on the metastable zones for systems with CuSO_4 or ZnSO_4 as the major component may be treated as a system of parallel lines². Results of this treatment are summarized in Table IV, where it is clearly seen that the addition of ZnSO_4 accelerates the nucleation of CuSO_4 (*cf.* systems 1 to 3) whereas the addition of CuSO_4 retards the nucleation of ZnSO_4 (*cf.* systems 4 to 6).

The effect of the formation of a solid solution on the rate of crystal growth is far less pronounced. The values of k_G listed in Table III suggest that the crystals of both types of solid solution probably grow somewhat more rapidly than do the pure components, but the experimental data are too scattered to permit the difference to be determined with any certainty. There is a distinct effect of the solution flow rate, suggesting that the crystal growth is controlled by diffusion in the surface layer. The effect of the solution flow rate on the crystal growth rate is usually described by the Frössling equation⁸

TABLE III
Crystal growth rates

System No	v cm s^{-1}	Number of runs	$10^6 L/\Delta w$	Fig. No	$10^3 k_G^a$
7	2.6	22	4.43	3	2.9 ± 0.65
	4.0	5	7.28	3	4.8 ± 1.3
	5.0	12	10.76	3	7.1 ± 1.3
8	2.6	7	5.5	4	3.67 ± 0.66
	5.0	8	10.1	4	6.6 ± 1.0
9	1.8	3	2.03	5	2.52 ± 0.25
	2.8	6	2.15	5	2.66 ± 0.61
10	1.8	10	2.14	6	2.65 ± 0.37
	2.8	9	2.43	6	3.01 ± 0.62

^a Supplemented with the standard deviation.

$$\frac{k_G L}{D} = c \left(\frac{v \varrho_1 L}{\eta} \right)^a \left(\frac{\eta}{\varrho_1 D} \right)^{1/3} \quad (9)$$

which, for our purposes, may be simplified to

$$\log k_G = \text{constant} + a \log v. \quad (10)$$

As can be seen from Fig. 7, a straight line of slope $a = 0.92$ can be drawn through the experimental points. The slope usually quoted in the literature is $a = 0.6$, and the corresponding straight lines are drawn in Fig. 7 as dashed lines.

TABLE IV
Metastable zone widths at constant n

System No	n	A	ΔT_{\max}			$k_N \cdot 10^2$	$k_N^{1/n}$
			$-\dot{T} = 2$	5	20		
1	2.90	1.7303	4.05	5.55	8.95	4.98	0.355
(2	2.90	1.4090	1.93	2.65	4.27	16.08	0.532)
3	2.90	1.6089	3.06	4.20	6.77	11.16	0.469
4	2.61	1.2728	1.06	1.51	2.56	2.81	0.255
5	2.61	1.4462	1.58	2.24	3.82	0.99	0.171
6	2.61	1.5514	2.01	2.86	4.86	0.53	0.134

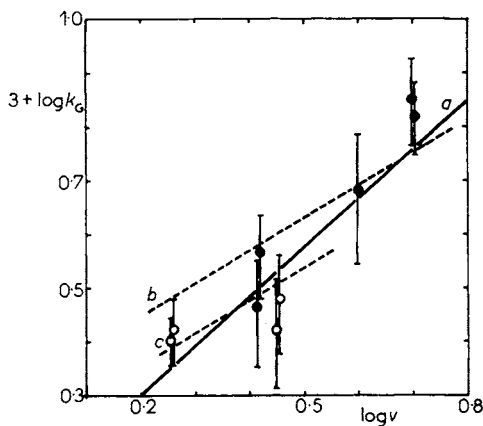


FIG. 7

The crystal growth rate as a function of the solution flow rate, v . a $a = 0.92$; b $a = 0.6$ for $\text{CuSO}_4 \cdot 5 \text{H}_2\text{O}$; c $a = 0.6$ for $\text{ZnSO}_4 \cdot 7 \text{H}_2\text{O}$; \circ $\text{ZnSO}_4 \cdot 7 \text{H}_2\text{O}$; \bullet $\text{CuSO}_4 \cdot 5 \text{H}_2\text{O}$. The bars represent maximum scatter of experimental data

In conclusion it may be summarized that the addition of Zn^{2+} to a solution of CuSO_4 increases both the nucleation and crystal growth rates, whereas the addition of Cu^{2+} to a solution of ZnSO_4 retards the nucleation rate and slightly increases the rate of crystal growth.

LIST OF SYMBOLS

A	constant in Eq. (2)
A_c	crystal surface area
a	exponent in Eq. (5)
c	constant
D	diffusion coefficient
g	growth order
k_G	growth rate constant
k_N	nucleation rate constant
L	crystal size
\dot{L}	linear crystallization rate
\dot{m}_G	crystal growth rate
m_0	initial crystal mass
m_f	final crystal mass
\dot{N}_N	nucleation rate
N_c	number of crystals
n	nucleation order
T	temperature
T_{eq}	temperature at which a solution is just saturated
$-\dot{T}$	cooling rate
ΔT_{max}	maximum undercooling
t	time period of measurement
v	upward flow rate of solution
w_{eq}	solubility
Δw	supersaturation
α	volume shape factor
β	surface shape factor
ρ_c	crystal density
ρ_1	solution density
η	viscosity

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